TEXAS INSTRUMENTS

SN74LVC3G34

SCES366L –AUGUST 2001–REVISED OCTOBER 2015

SN74LVC3G34 Triple Buffer Gate

1 Features

- Available in the Texas Instruments NanoFree™ Package
- Supports 5.5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.1 ns at 3.3 V
- Low Power Consumption, 10-µA Maximum I_{CC}
- ±24-mA Output Drive at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at V_{CC} = 3.3 V, T_A = 25°C
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Can Be Used as a Down Translator to Translate Inputs From a Maximum of 5.5 V Down to the V_{CC} Level
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

2 Applications

- AV Receivers
- Audio Docks: Portable
- Blu-ray Players and Home Theaters
- DVD Recorders and Players
- Embedded PCs
- MP3 Players and Recorders (Portable Audio)
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid-State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablets: Enterprise
- Video Analytics: Servers
- Wireless Headsets, Keyboards, and Mice

3 Description

The SN74LVC3G34 device is a triple buffer gate designed for 1.65-V to 5.5-V V_{CC} operation. The SN74LVC3G34 device performs the Boolean function Y = A in positive logic.

NanoFree package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LVC3G34DCT	SM8 (8)	2.95 mm × 2.80 mm
SN74LVC3G34DCU	VSSOP (8)	2.30 mm × 2.00 mm
SN74LVC3G34YZP	DSBGA (8)	1.91 mm × 0.91 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.
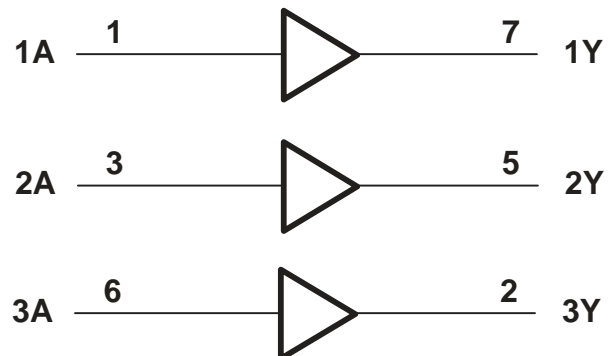
Simplified Schematic
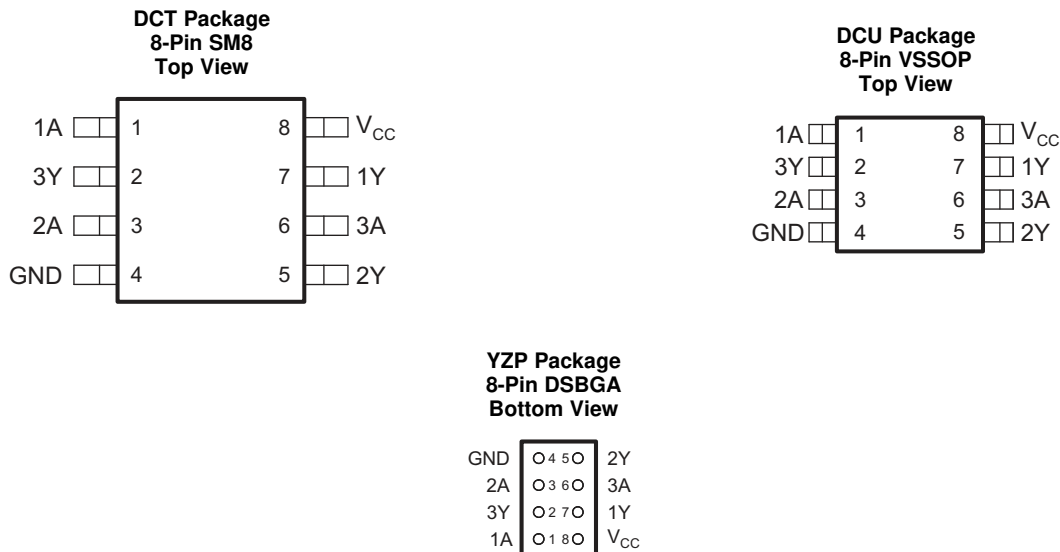
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision J (Feburary 2007) to Revision K   **Page**

- Updated document to new TI data sheet format. 1
- Removed *Ordering Information* table. 1
- Updated *Features* section 1
- Updated operating temperature range. 4

Changes from Revision K (November 2013) to Revision L   **Page**

- Added *Applications*, *Device Information* table, *Pin Configuration and Functions* section, *ESD Ratings* table, *Thermal Information* table, *Typical Characteristics* section, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section 1
- Deleted part number from *Switching Characteristics* table headers. 5

5 Pin Configuration and Functions

**DCT Package
8-Pin SM8
Top View**

1A	1	8 V$_{CC}$
3Y	2	7 1Y
2A	3	6 3A
GND	4	5 2Y

**DCU Package
8-Pin VSSOP
Top View**

1A	1	8 V$_{CC}$
3Y	2	7 1Y
2A	3	6 3A
GND	4	5 2Y

**YZP Package
8-Pin DSBGA
Bottom View**

GND	4 5	2Y
2A	3 6	3A
3Y	2 7	1Y
1A	1 8	V$_{CC}$

Pin Functions[1]

PIN		I/O	DESCRIPTION
NAME	NO.		
1A	1	I	Buffer Input 1
1Y	7	O	Buffer Output 1
2A	3	I	Buffer Input 2
2Y	5	O	Buffer Output 2
3A	6	I	Buffer Input 3
3Y	2	O	Buffer Output 3
GND	4	—	Ground pin
V$_{CC}$	8	—	Power pin

(1) See mechanical drawings for dimensions

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

			MIN	MAX	UNIT
V$_{CC}$	Supply voltage		−0.5	6.5	V
V$_I$	Input voltage[2]		−0.5	6.5	V
V$_O$	Voltage applied to any output in the high-impedance or power-off state[2]		−0.5	6.5	V
V$_O$	Voltage applied to any output in the high or low state[2][3]		−0.5	V$_{CC}$ + 0.5	V
I$_{IK}$	Input clamp current	V$_I$ < 0		−50	mA
I$_{OK}$	Output clamp current	V$_O$ < 0		−50	mA
I$_O$	Continuous output current			±50	mA
	Continuous current through V$_{CC}$ or GND			±100	mA
T$_J$	Junction temperature			150	°C
T$_{stg}$	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(3) The value of V$_{CC}$ is provided in the *Recommended Operating Conditions* table.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1]	2500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101, all pins[2]	1500	

(1)   JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions[1]

			MIN	MAX	UNIT
V_{CC}	Supply voltage	Operating	1.65	5.5	V
		Data retention only	1.5		
V_{IH}	High-level input voltage	V_{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		V
		V_{CC} = 2.3 V to 2.7 V	1.7		
		V_{CC} = 3 V to 3.6 V	2		
		V_{CC} = 4.5 V to 5.5 V	$0.7 \times V_{CC}$		
V_{IL}	Low-level input voltage	V_{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V		0.7	
		V_{CC} = 3 V to 3.6 V		0.8	
		V_{CC} = 4.5 V to 5.5 V		$0.3 \times V_{CC}$	
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 1.65 V		–4	mA
		V_{CC} = 2.3 V		–8	
		V_{CC} = 3 V		–16	
				–24	
		V_{CC} = 4.5 V		–32	
I_{OL}	Low-level output current	V_{CC} = 1.65 V		4	mA
		V_{CC} = 2.3 V		8	
		V_{CC} = 3 V		16	
				24	
		V_{CC} = 4.5 V		32	
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	ns/V
		V_{CC} = 3.3 V ± 0.3 V		10	
		V_{CC} = 5 V ± 0.5 V		5	
T_A	Operating free-air temperature	DCT, DCU Package	–40	125	°C
		YZP Package	-40	85	

(1)   All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

6.4 Thermal Information

THERMAL METRIC[1]		SN74LVC3G34			UNIT
		DCT (SM8)	DCU (VSSOP)	YZP (DSBGA)	
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	220	227	140	°C/W

(1)   For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V_{CC}	MIN	TYP[1]	MAX	UNIT
V_{OH}		I_{OH} = −100 µA		1.65 V to 5.5 V	V_{CC} − 0.1			V
		I_{OH} = −4 mA		1.65 V	1.2			
		I_{OH} = −8 mA		2.3 V	1.9			
		I_{OH} = −16 mA		3 V	2.4			
		I_{OH} = −24 mA			2.3			
		I_{OH} = −32 mA		4.5 V	3.8			
V_{OL}		I_{OL} = 100 µA		1.65 V to 5.5 V			0.1	V
		I_{OL} = 4 mA		1.65 V			0.45	
		I_{OL} = 8 mA		2.3 V			0.3	
		I_{OL} = 16 mA		3 V			0.4	
		I_{OL} = 24 mA	T_A = −40°C to 85°C	3 V			0.55	
			T_A = −40°C to 125°C				0.75	
		I_{OL} = 32 mA	T_A = −40°C to 85°C	4.5 V			0.55	
			T_A = −40°C to 125°C				0.75	
I_I	A inputs	V_I = 5.5 V or GND		0 to 5.5 V			±5	µA
I_{off}		V_I or V_O = 5.5 V		0			±10	µA
I_{CC}		V_I = 5.5 V or GND, I_O = 0		1.65 V to 5.5 V			10	µA
ΔI_{CC}		One input at V_{CC} − 0.6 V, Other inputs at V_{CC} or GND		3 V to 5.5 V			500	µA
C_I		V_I = V_{CC} or GND	T_A = −40°C to 85°C	3.3 V		3.5		pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

6.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)
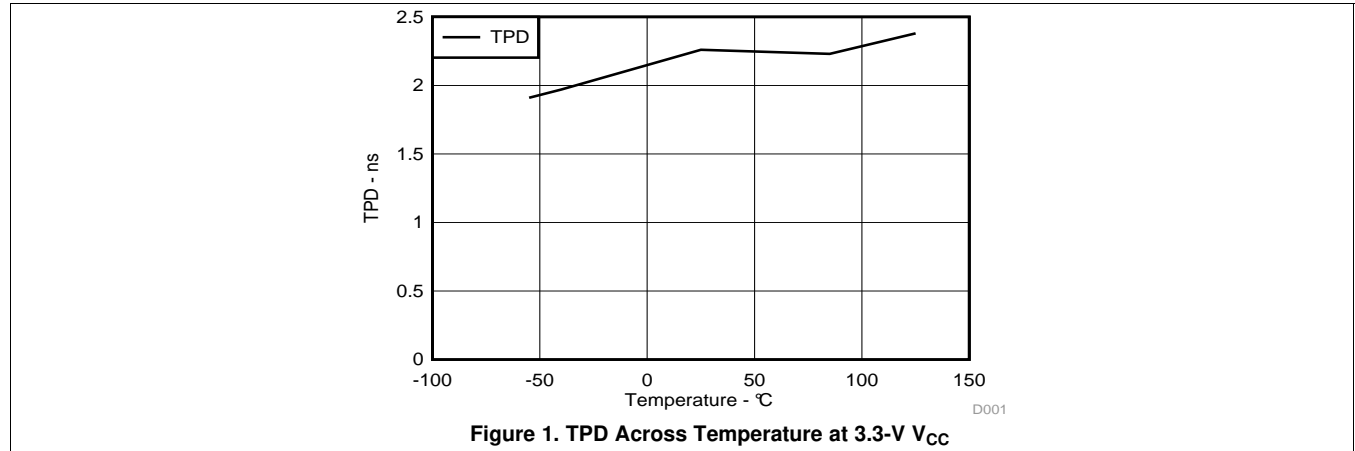
PARAMETER	FROM (INPUT)	TO (OUTPUT)	OPERATING FREE-AIR TEMPERATURE (T_A)	V_{CC}	MIN	MAX	UNIT
t_{pd}	A	Y	−40°C to 85°C	V_{CC} = 1.8 V ± 0.15 V	3.2	7.9	ns
				V_{CC} = 2.5 V ± 0.2 V	1.5	4.4	
				V_{CC} = 3.3 V ± 0.3 V	1.4	4.1	
				V_{CC} = 5 V ± 0.5 V	1.1	3.2	
t_{pd}	A	Y	−40°C to 125°C	V_{CC} = 1.8 V ± 0.15 V	3.2	8.9	ns
				V_{CC} = 2.5 V ± 0.2 V	1.5	5.4	
				V_{CC} = 3.3 V ± 0.3 V	1.4	5.1	
				V_{CC} = 5 V ± 0.5 V	1.1	3.8	

6.7 Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS	V_{CC}	TYP	UNIT
C_{pd}	Power dissipation capacitance	f = 10 MHz	V_{CC} = 1.8 V	19	pF
			V_{CC} = 2.5 V	19	
			V_{CC} = 3.3 V	19	
			V_{CC} = 5 V	21	

6.8 Typical Characteristics

Figure 1. TPD Across Temperature at 3.3-V V$_{CC}$

Product Folder Links: *SN74LVC3G34*

7 Parameter Measurement Information
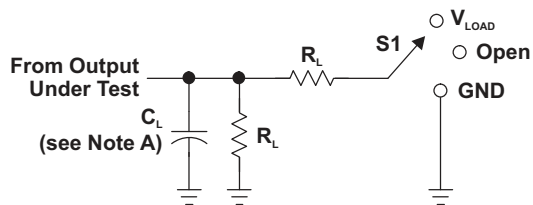
LOAD CIRCUIT

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

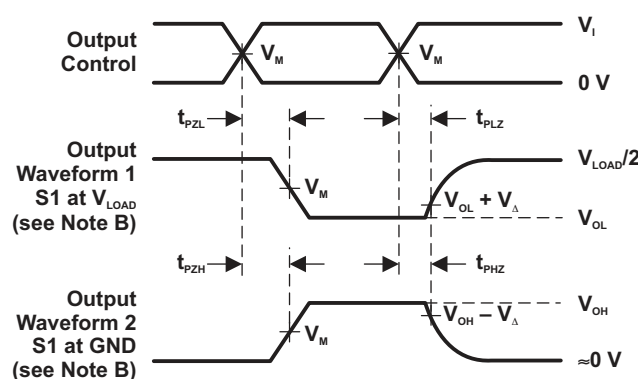| V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_Δ
	V_I	t_r/t_f					
1.8 V ± 0.15 V	V_{CC}	≤2 ns	$V_{CC}/2$	2 × V_{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V_{CC}	≤2 ns	$V_{CC}/2$	2 × V_{CC}	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V ± 0.5 V	V_{CC}	≤2.5 ns	$V_{CC}/2$	2 × V_{CC}	50 pF	500 Ω	0.3 V
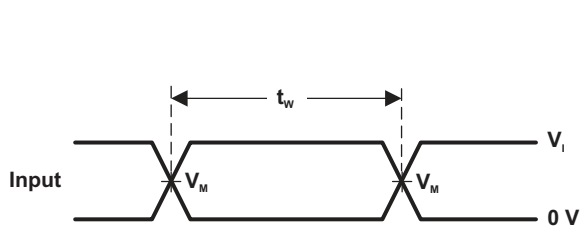
**VOLTAGE WAVEFORMS
PULSE DURATION**
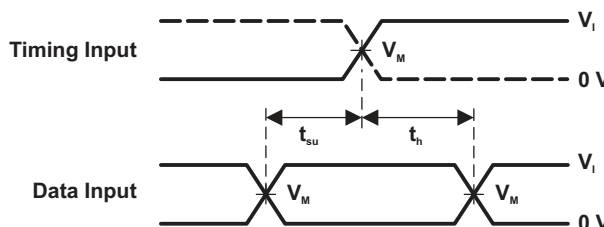
**VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES**
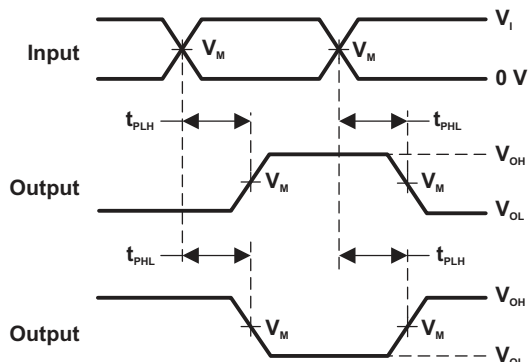
**VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS**

**VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING**

NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
 Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω.
 D. The outputs are measured one at a time, with one transition per measurement.
 E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 F. t_{PZL} and t_{PZH} are the same as t_{en}.
 G. t_{PLH} and t_{PHL} are the same as t_{pd}.
 H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

The SN74LVC3G34 device contains three buffer gates that each perform the Boolean function Y = A. This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

8.2 Functional Block Diagram
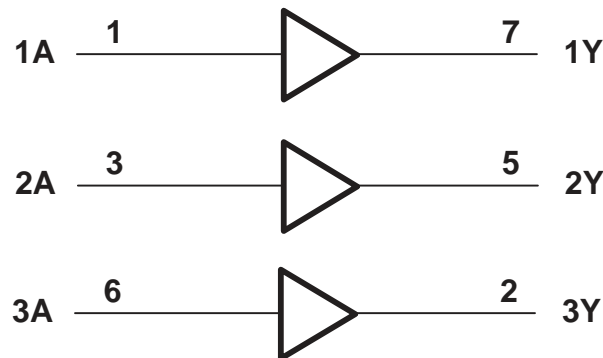
8.3 Feature Description

The SN74LVC3G34 device has a wider operating voltage range, operating from 1.65 V to 5.5 V, and allows down voltage translation. The SN74LVC3G34 I_{off} feature allows voltages on the inputs and outputs when V_{CC} is 0 V.

8.4 Device Functional Modes

Table 1 lists the functional modes of the SN74LVC3G34.

Table 1. Function Table

INPUT A	OUTPUT Y
H	H
L	L

9 Application and Implementation

9.1 Application Information

The SN74LVC3G34 is a high-drive CMOS device that can be used as a buffer with a high output drive, such as an LED application. It can produce 24 mA of drive current at 3.3 V, making it ideal for driving multiple outputs and good for high-speed applications up to 100 MHz. The inputs are 5.5-V tolerant, allowing it to translate down to V_{CC}.

9.2 Typical Application
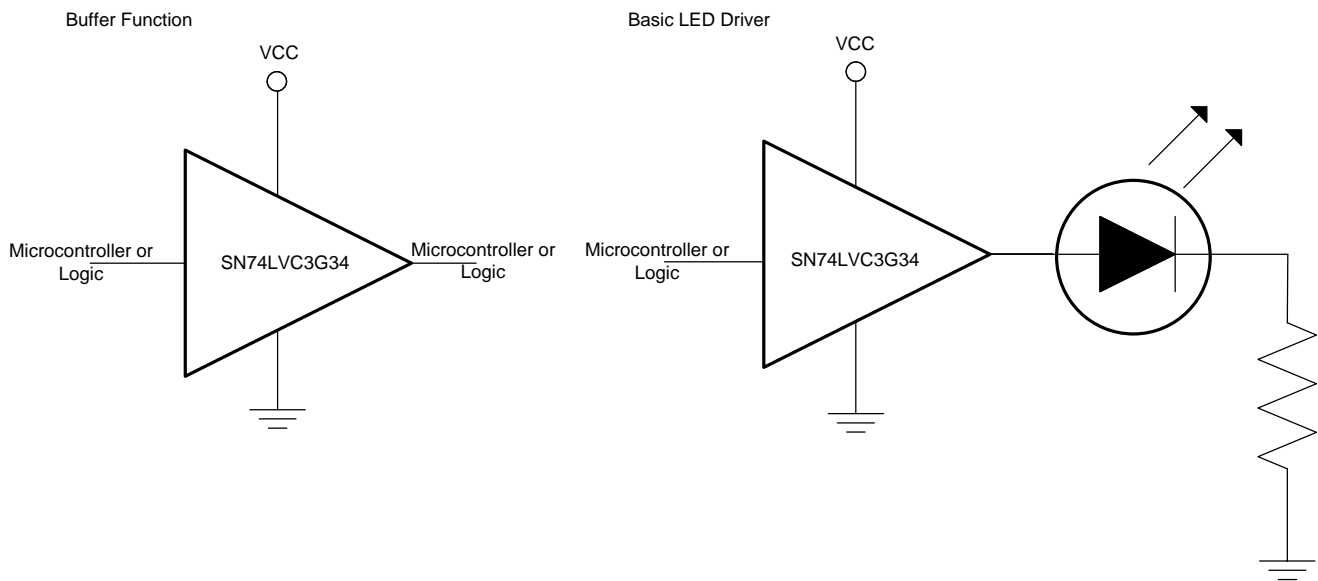

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions must be considered to prevent ringing.

9.2.2 Detailed Design Procedure

1. Recommended Input Conditions
   - Rise time and fall time specs. See ($\Delta t/\Delta V$) in the *Recommended Operating Conditions* table.
   - Specified high and low levels. See (V_{IH} and V_{IL}) in the *Recommended Operating Conditions* table.
   - Inputs are overvoltage tolerant allowing them to go as high as (VI max) in the *Recommended Operating Conditions* table at any valid V_{CC}.
2. Recommended Output Conditions
   - Load currents must not exceed (I_O max) per output and must not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the *Recommended Operating Conditions* table.
   - Outputs must not be pulled above V_{CC} under normal operating conditions.

Typical Application (continued)

9.2.3 Application Curve

Figure 3. TPD Across V$_{CC}$ at 25°C
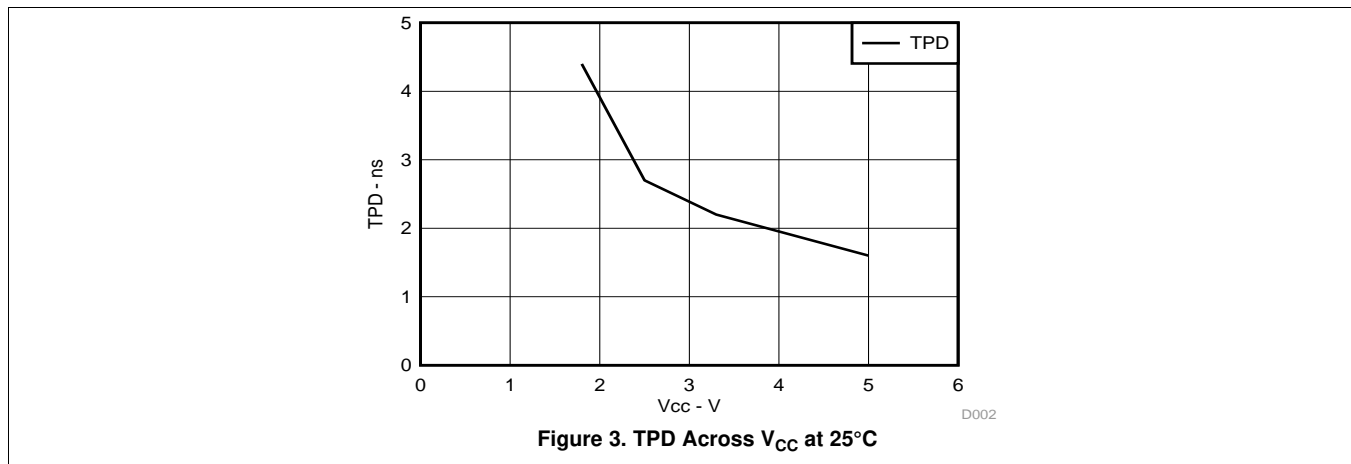
10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions* table.

Each V$_{CC}$ pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1-μF capacitor is recommended and if there are multiple V$_{CC}$ pins then a 0.01-μF or 0.022-μF capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1-μF and 1-μF capacitors are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices inputs must not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V$_{CC}$ whichever make more sense or is more convenient.

11.2 Layout Example

Product Folder Links: *SN74LVC3G34*
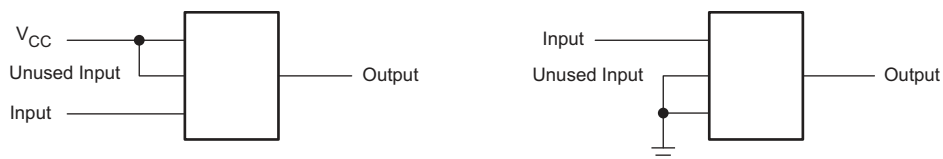
12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Documentation Support

For related documentation, see the following:

> *Implications of Slow or Floating CMOS Inputs*, SCBA004

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

NanoFree, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — *TI Glossary*.

> This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC3G34DCTR	ACTIVE	SM8	DCT	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C34 (R, Z)	Samples
SN74LVC3G34DCTRG4	ACTIVE	SM8	DCT	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C34 (R, Z)	Samples
SN74LVC3G34DCUR	ACTIVE	VSSOP	DCU	8	3000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	(34, C34J, C34Q, C 34R) (CR, CZ)	Samples
SN74LVC3G34DCURG4	ACTIVE	VSSOP	DCU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C34R	Samples
SN74LVC3G34DCUT	ACTIVE	VSSOP	DCU	8	250	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	(C34J, C34Q, C34R) CR	Samples
SN74LVC3G34DCUTG4	ACTIVE	VSSOP	DCU	8	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C34R	Samples
SN74LVC3G34YZPR	ACTIVE	DSBGA	YZP	8	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	C9N	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance
do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may
reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based
flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
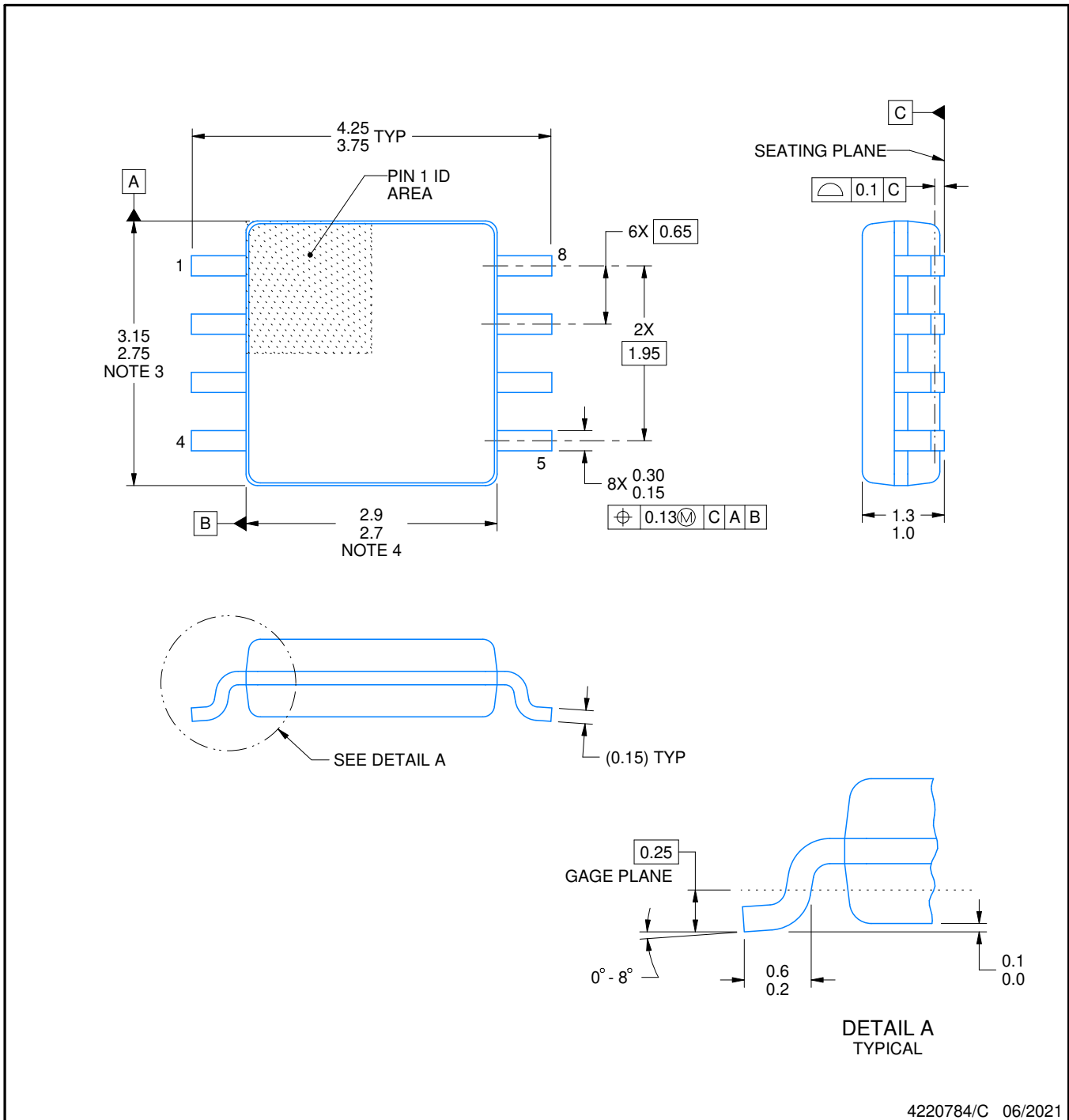
User Direction of Feed

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC3G34DCTR	SM8	DCT	8	3000	180.0	13.0	3.35	4.5	1.55	4.0	12.0	Q3
SN74LVC3G34DCUR	VSSOP	DCU	8	3000	178.0	9.5	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC3G34DCUR	VSSOP	DCU	8	3000	178.0	9.0	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC3G34DCUR	VSSOP	DCU	8	3000	180.0	9.0	2.25	3.4	1.0	4.0	8.0	Q3
SN74LVC3G34DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC3G34DCUT	VSSOP	DCU	8	250	178.0	9.0	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC3G34DCUT	VSSOP	DCU	8	250	178.0	9.5	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC3G34DCUTG4	VSSOP	DCU	8	250	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC3G34YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC3G34DCTR	SM8	DCT	8	3000	182.0	182.0	20.0
SN74LVC3G34DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74LVC3G34DCUR	VSSOP	DCU	8	3000	180.0	180.0	18.0
SN74LVC3G34DCUR	VSSOP	DCU	8	3000	182.0	182.0	20.0
SN74LVC3G34DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74LVC3G34DCUT	VSSOP	DCU	8	250	180.0	180.0	18.0
SN74LVC3G34DCUT	VSSOP	DCU	8	250	202.0	201.0	28.0
SN74LVC3G34DCUTG4	VSSOP	DCU	8	250	202.0	201.0	28.0
SN74LVC3G34YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

4.25 / 3.75 TYP

A

PIN 1 ID AREA

1

3.15 / 2.75 NOTE 3

4

B

2.9 / 2.7 NOTE 4

6X 0.65

8

2X 1.95

5

8X 0.30 / 0.15

⊕ 0.13 Ⓜ C A B

C

SEATING PLANE

⌒ 0.1 C

1.3 / 1.0

SEE DETAIL A

(0.15) TYP

0.25

GAGE PLANE

0° - 8°

0.6 / 0.2

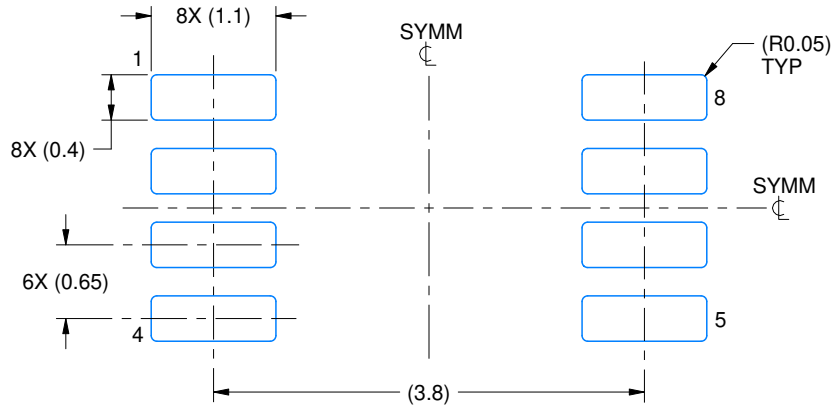0.1 / 0.0

DETAIL A
TYPICAL

4220784/C 06/2021

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.

TEXAS INSTRUMENTS
www.ti.com

8X (1.1)

SYMM

(R0.05)
TYP

1

8

8X (0.4)

SYMM

6X (0.65)

4

5

(3.8)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.07 MAX
ALL AROUND

0.07 MIN
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED
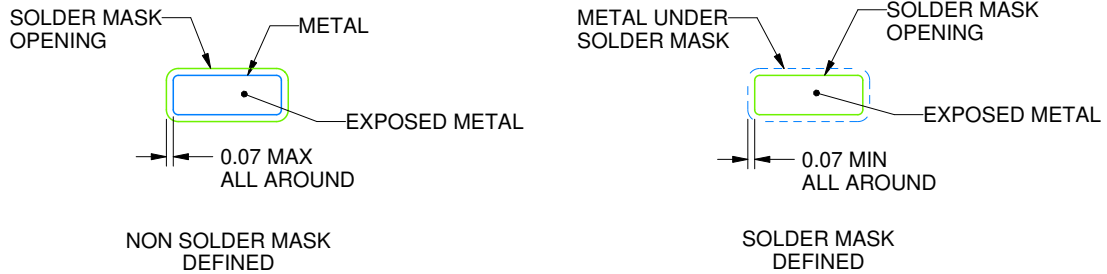
SOLDER MASK DETAILS

4220784/C   06/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (1.1)

SYMM

1

8X (0.4)

8

SYMM

6X (0.65)

4

5

(3.8)
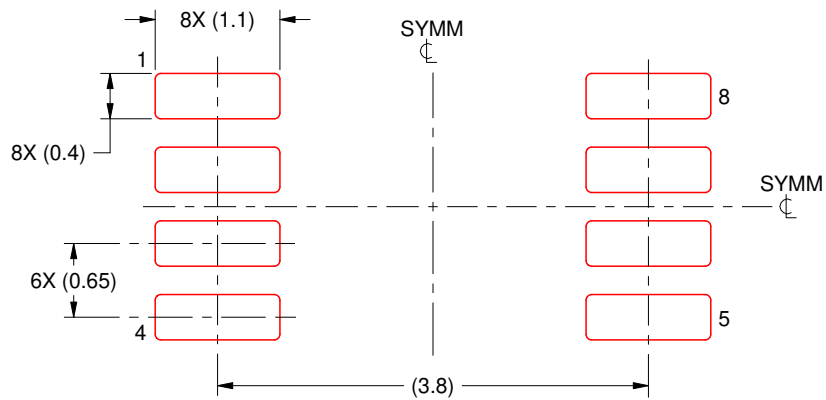
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
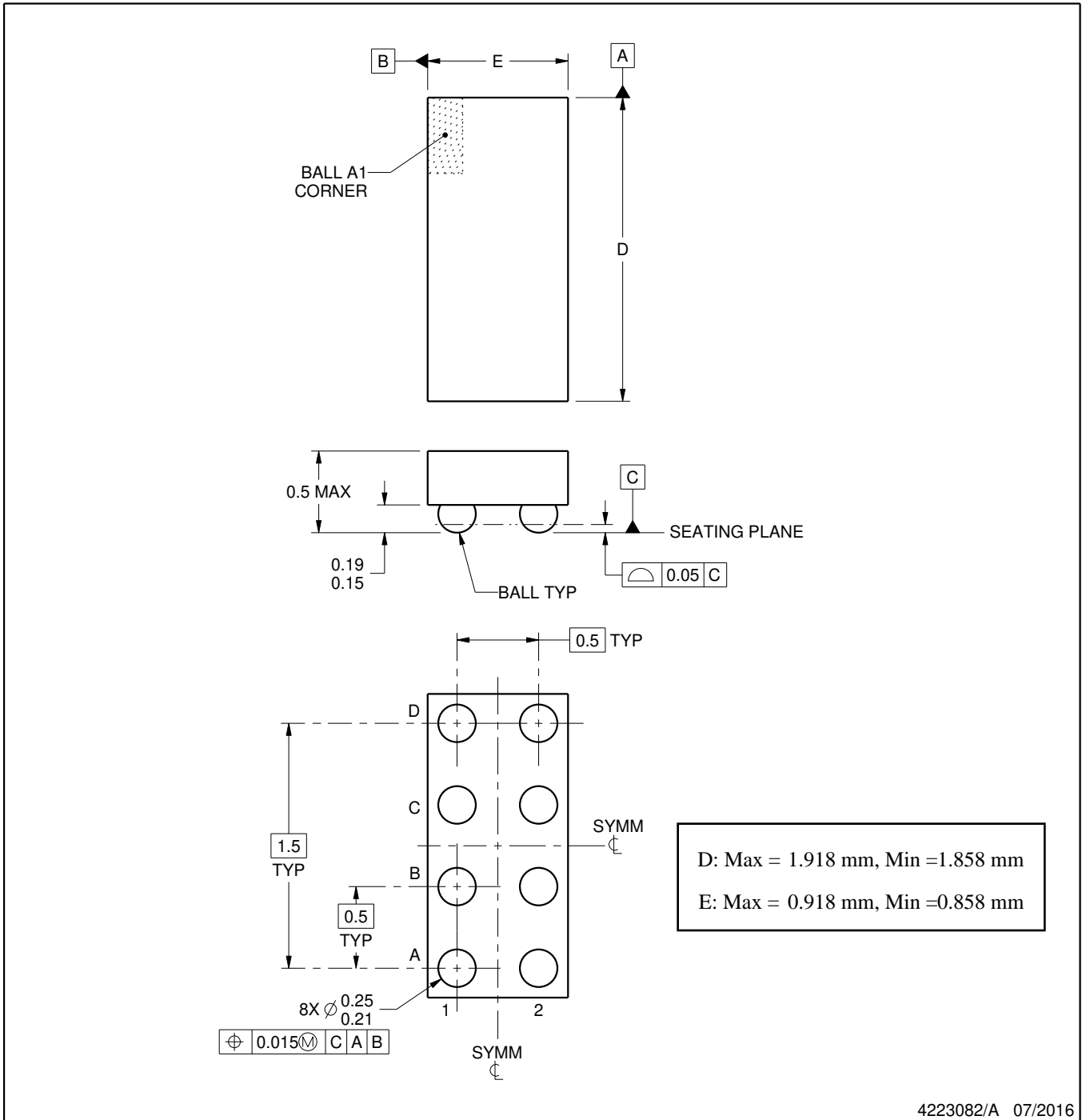SCALE:15X

4220784/C   06/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
design recommendations.
8. Board assembly site may have different recommendations for stencil design.

B ◄── E ──► A

BALL A1
CORNER

D

0.5 MAX

C

SEATING PLANE

0.19
0.15

◠ | 0.05 | C

BALL TYP

0.5 | TYP

D

C

SYMM
₵

1.5
TYP

B

D: Max = 1.918 mm, Min =1.858 mm

E: Max = 0.918 mm, Min =0.858 mm

0.5
TYP

A

8X ⌀ 0.25
0.21

1   2

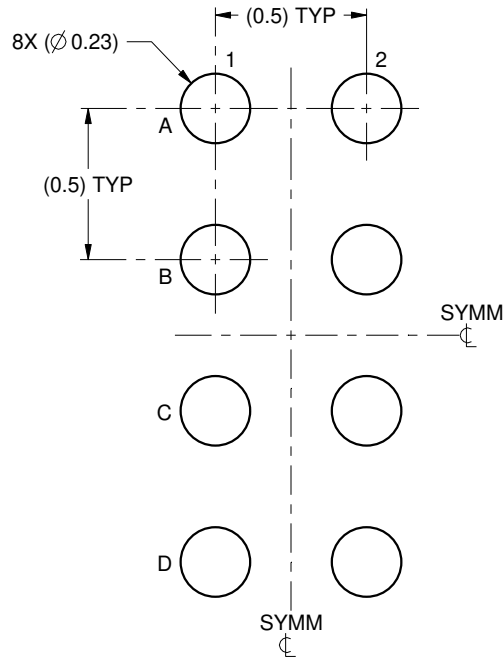⊕ | 0.015Ⓜ | C | A | B

SYMM
₵

4223082/A   07/2016

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
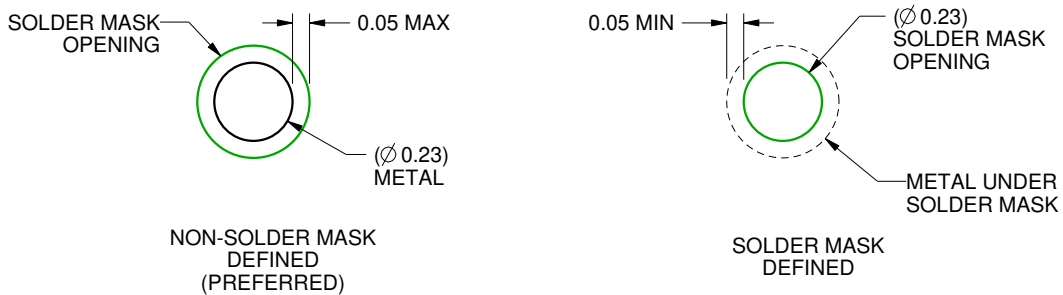2. This drawing is subject to change without notice.

8X ($\varnothing$ 0.23)

(0.5) TYP

(0.5) TYP

1 2

A

B

C

D

SYMM

SYMM
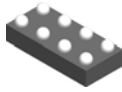
LAND PATTERN EXAMPLE
SCALE:40X

SOLDER MASK
OPENING

0.05 MAX

($\varnothing$ 0.23)
METAL

**NON-SOLDER MASK
DEFINED
(PREFERRED)**

0.05 MIN

($\varnothing$ 0.23)
SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

**SOLDER MASK
DEFINED**

SOLDER MASK DETAILS
NOT TO SCALE

4223082/A   07/2016

NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
   For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).
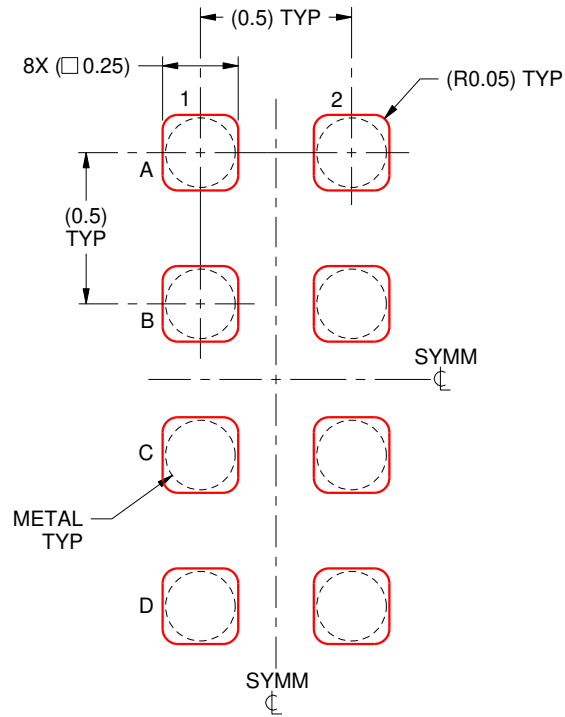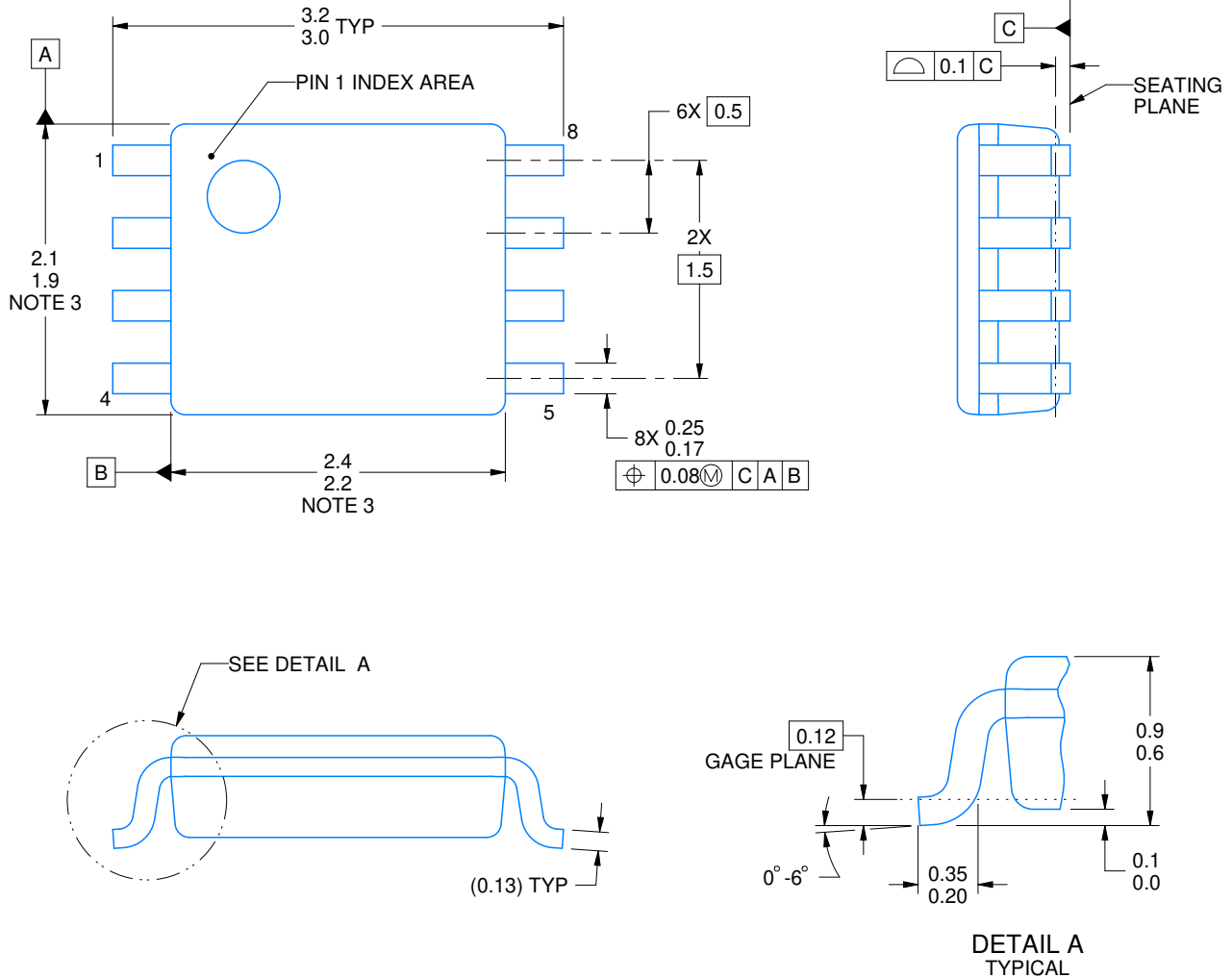
SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4223082/A   07/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

3.2
3.0 TYP

A

PIN 1 INDEX AREA

1

2.1
1.9
NOTE 3

4

8

6X 0.5

2X
1.5

5

8X 0.25
0.17

⊕ 0.08Ⓜ C A B

B

2.4
2.2
NOTE 3

C

◯ 0.1 C

SEATING
PLANE

SEE DETAIL A

(0.13) TYP

0.12
GAGE PLANE

0°-6°

0.35
0.20

0.9
0.6

0.1
0.0

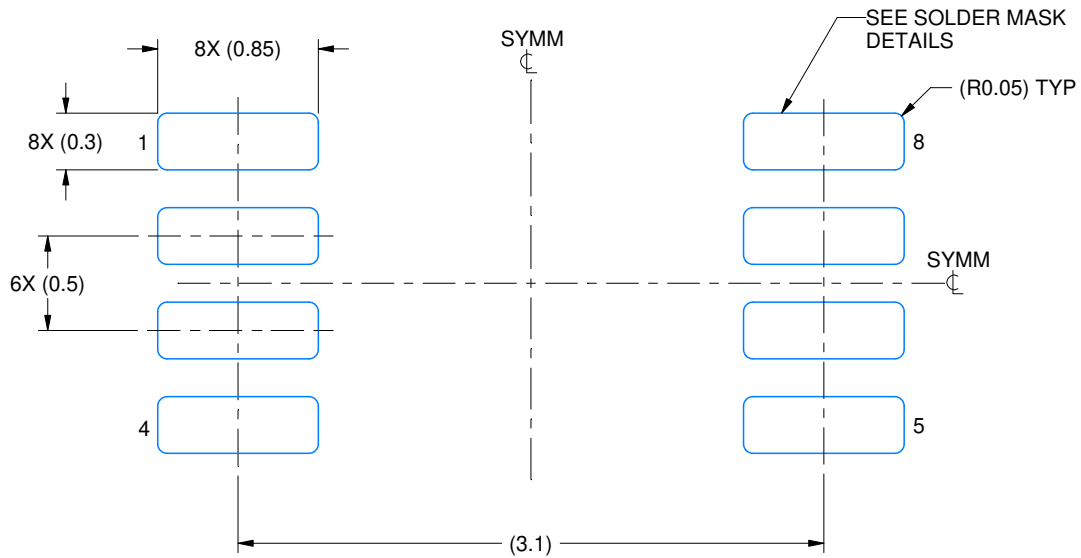DETAIL A
TYPICAL

4225266/A 09/2014

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
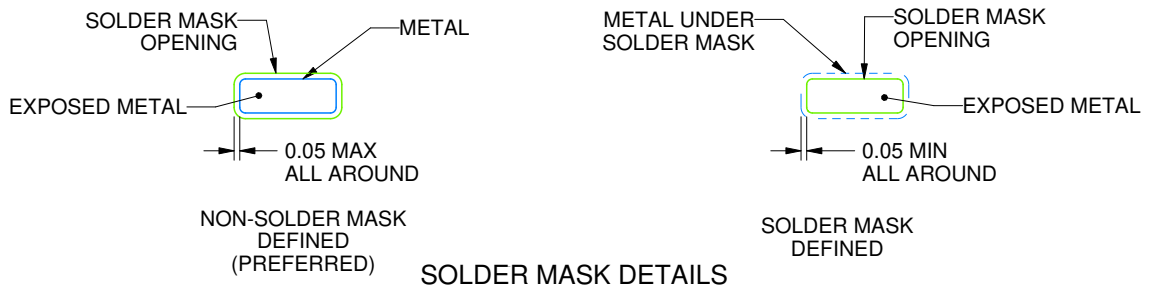4. Reference JEDEC registration MO-187 variation CA.

SEE SOLDER MASK
DETAILS

SYMM

8X (0.85)

(R0.05) TYP

8X (0.3)   1

8

SYMM

6X (0.5)

4

5

(3.1)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED

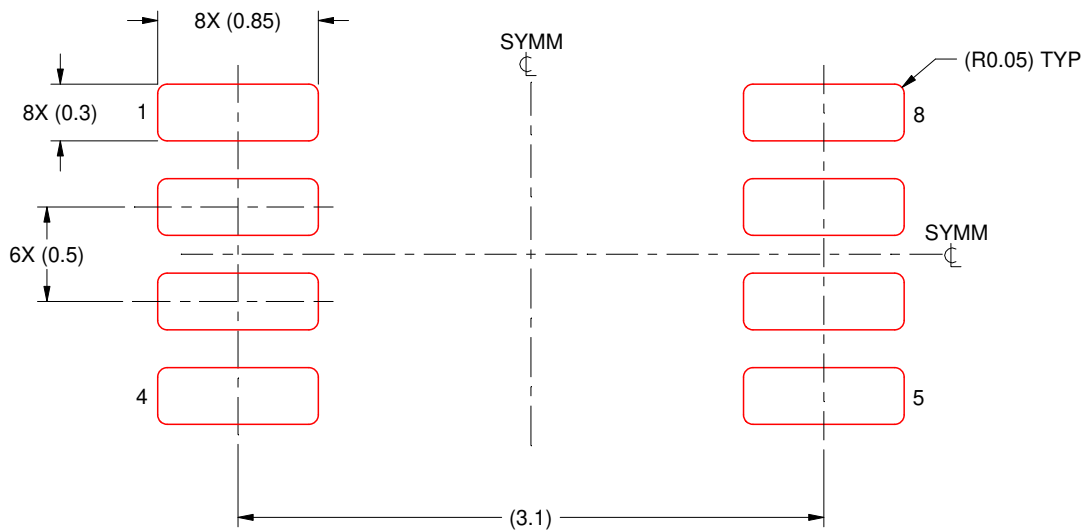**SOLDER MASK DETAILS**

4225266/A   09/2014

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (0.85)

SYMM

(R0.05) TYP

8X (0.3)   1

8

6X (0.5)

SYMM

4

5

(3.1)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

4225266/A   09/2014

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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